

## MJD122

### D-PAK for Surface Mount Applications

- High DC Current Gain
- Built-in a Damper Diode at E-C
- Lead Formed for Surface Mount Applications (No Suffix)
- Straight Lead (I-PAK, " - I " Suffix)
- Electrically Similar to Popular TIP122
- Complement to MJD127

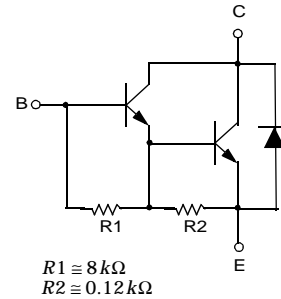


### NPN Silicon Darlington Transistor

#### Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

| Symbol    | Parameter  | Value      | Units            |
|-----------|--|------------|------------------|
| $V_{CBO}$ | Collector-Base Voltage                           | 100        | V                |
| $V_{CEO}$ | Collector-Emitter Voltage                        | 100        | V                |
| $V_{EBO}$ | Emitter-Base Voltage                             | 5          | V                |
| $I_C$     | Collector Current (DC)                           | 8          | A                |
| $I_{CP}$  | Collector Current (Pulse)                        | 16         | A                |
| $I_B$     | Base Current                                     | 120        | mA               |
| $P_C$     | Collector Dissipation ( $T_C=25^\circ\text{C}$ ) | 20         | W                |
|           | Collector Dissipation ( $T_a=25^\circ\text{C}$ ) | 1.75       | W                |
| $T_J$     | Junction Temperature                             | 150        | $^\circ\text{C}$ |
| $T_{STG}$ | Storage Temperature                              | - 65 ~ 150 | $^\circ\text{C}$ |

Equivalent Circuit



#### Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

| Symbol         | Parameter                             | Test Condition  | Min.        | Max. | Units         |
|----------------|---------------------------------------|---|-------------|------|---------------|
| $V_{CEO(sus)}$ | *Collector-Emitter Sustaining Voltage | $I_C = 30\text{mA}, I_B = 0$  | 100         |      | V             |
| $I_{CEO}$      | Collector Cut-off Current             | $V_{CE} = 50\text{V}, I_B = 0$  |             | 10   | $\mu\text{A}$ |
| $I_{CBO}$      | Collector Cut-off Current             | $V_{CB} = 100\text{V}, I_E = 0$   |             | 10   | $\mu\text{A}$ |
| $I_{EBO}$      | Emitter Cut-off Current               | $V_{EB} = 5\text{V}, I_C = 0$   |             | 2    | mA            |
| $h_{FE}$       | *DC Current Gain                      | $V_{CE} = 4\text{V}, I_C = 4\text{A}$<br>$V_{CE} = 4\text{V}, V_{EB} = 8\text{A}$ | 1000<br>100 | 12K  |               |
| $V_{CE(sat)}$  | *Collector-Emitter Saturation Voltage | $I_C = 4\text{A}, I_B = 16\text{mA}$  |             | 2    | V             |
|                |                                       | $I_C = 8\text{A}, I_B = 80\text{mA}$  |             | 4    | V             |
| $V_{BE(sat)}$  | *Base-Emitter Saturation Voltage      | $I_C = 8\text{A}, I_B = 80\text{mA}$  |             | 4.5  | V             |
| $V_{BE(on)}$   | *Base-Emitter ON Voltage              | $V_{CE} = 4\text{V}, I_C = 4\text{A}$   |             | 2.8  | V             |
| $C_{ob}$       | Output Capacitance                    | $V_{CB} = 10\text{V}, I_E = 0$<br>$f = 0.1\text{MHz}$                             |             | 200  | pF            |

\* Pulse Test:  $PW \leq 300\mu\text{s}$ , Duty Cycles  $\leq 2\%$

# Typical Characteristics

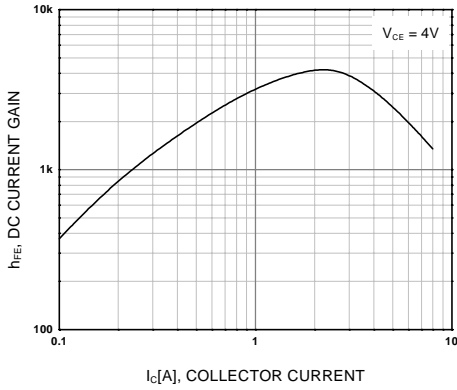


Figure 1. DC current Gain

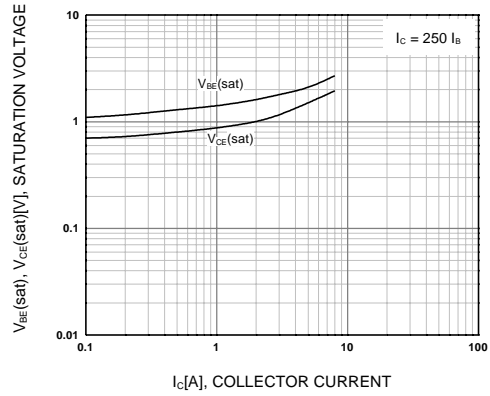


Figure 2. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

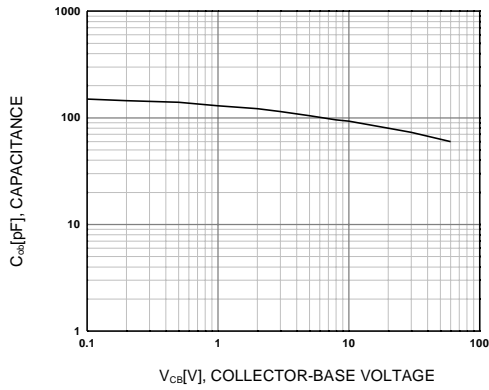


Figure 3. Collector Output Capacitance

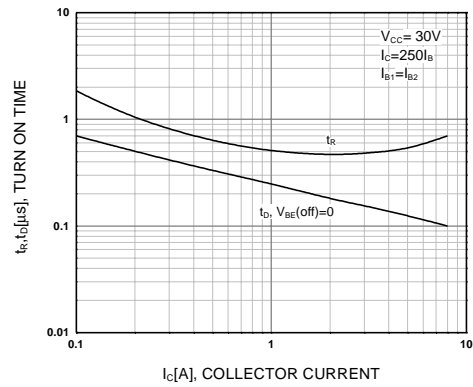


Figure 4. Turn On Time

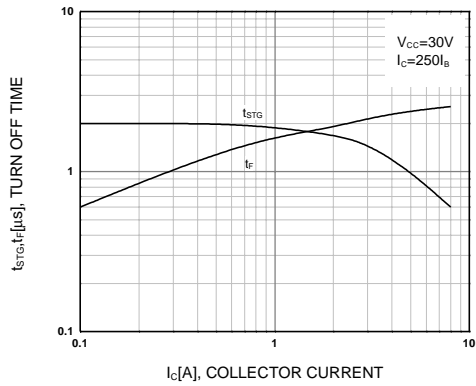


Figure 5. Turn Off Time

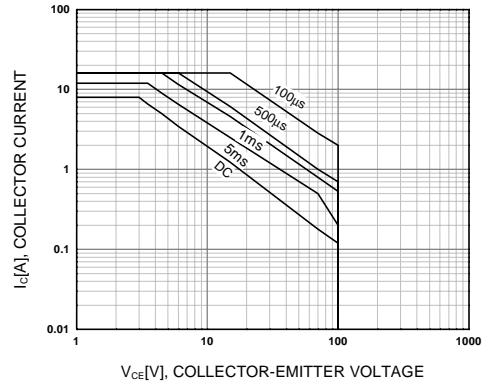


Figure 6. Safe Operating Area

# Typical Characteristics (Continued)

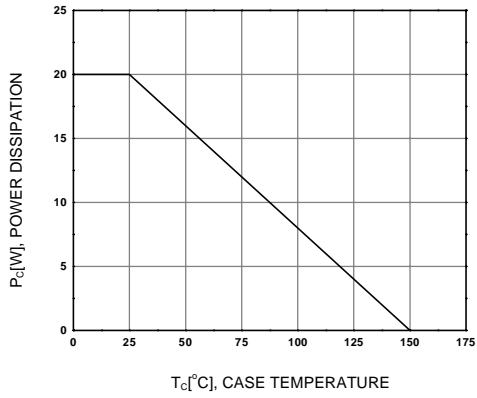
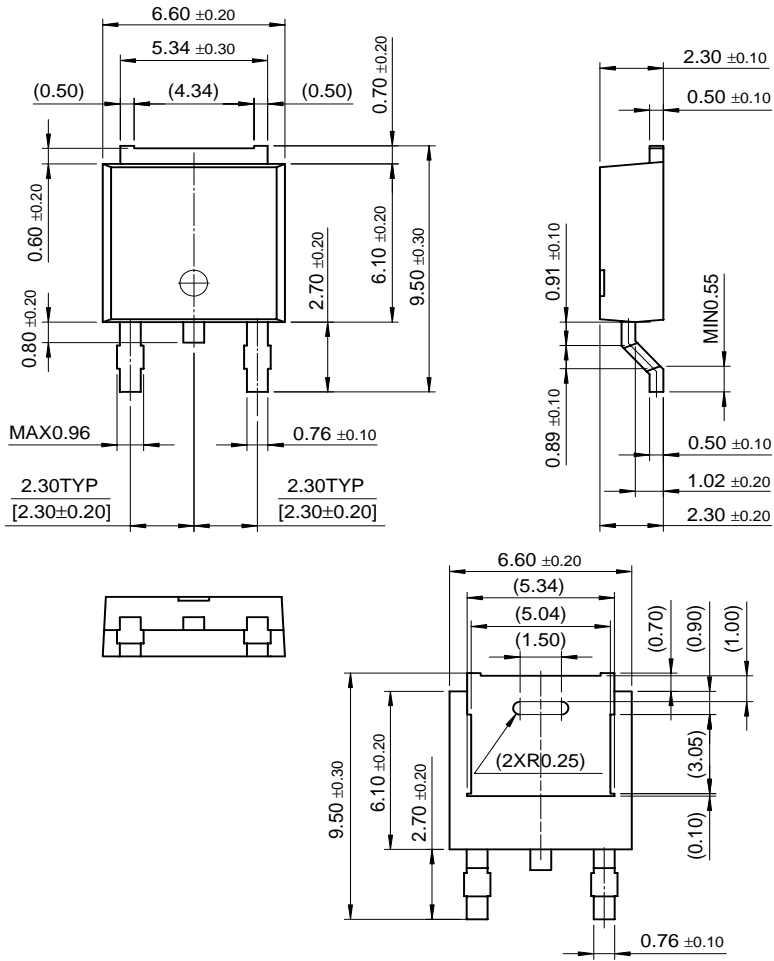


Figure 7. Power Derating

# Package Dimensions

MJD122

## D-PAK



Dimensions in Millimeters

## TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

|                      |                     |                              |                       |
|----------------------|---------------------|------------------------------|-----------------------|
| ACE <sup>x</sup> ™   | FAST <sup>®</sup>   | OPTOPLANAR™                  | STAR*POWER™           |
| Bottomless™          | FAST <sup>r</sup> ™ | PACMAN™                      | Stealth™              |
| CoolFET™             | FRFET™              | POP™                         | SuperSOT™-3           |
| CROSSVOLT™           | GlobalOptoisolator™ | Power247™                    | SuperSOT™-6           |
| DenseTrench™         | GTO™                | PowerTrench <sup>®</sup>     | SuperSOT™-8           |
| DOME™                | HiSeC™              | QFET™                        | SyncFET™              |
| EcoSPARK™            | ISOPLANAR™          | QS™                          | TruTranslation™       |
| E <sup>2</sup> CMOS™ | LittleFET™          | QT Optoelectronics™          | TinyLogic™            |
| EnSigna™             | MicroFET™           | Quiet Series™                | UHC™                  |
| FACT™                | MICROWIRE™          | SLIENT SWITCHER <sup>®</sup> | UltraFET <sup>®</sup> |
| FACT Quiet Series™   | OPTOLOGIC™          | SMART START™                 | VCX™                  |

STAR\*POWER is used under license

## DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

## LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

## PRODUCT STATUS DEFINITIONS

### Definition of Terms

| Datasheet Identification | Product Status         | Definition  |
|--------------------------|------------------------|---|
| Advance Information      | Formative or In Design | This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.  |
| Preliminary              | First Production       | This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design. |
| No Identification Needed | Full Production        | This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.   |
| Obsolete                 | Not In Production      | This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.   |